VS-95PF(R)...(W) High Voltage Series

Vishay Semiconductors

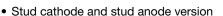
Standard Recovery Diodes Generation 2 DO-5 (DO-203AB) (Stud Version), 95 A



PRIMARY CHARACTERISTICS			
I _{F(AV)}	95 A		
Package	DO-5 (DO-203AB)		
Circuit configuration	Single		

FEATURES

- High surge current capability
- · Designed for a wide range of applications





- Wire version available
- Low thermal resistance
- · Designed and qualified for multiple level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- Welding
- Any high voltage input rectification bridge

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
		95	A	
I _{F(AV)}	T _C	128	°C	
I _{F(RMS)}		149	A	
	50 Hz	1700		
I _{FSM}	60 Hz	1800	A	
l ² t	50 Hz	14 500	A ² s	
	60 Hz	13 500	— A-S	
V _{RRM}	Range	1400 to 1600	V	
TJ		-55 to +150	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE VRRM, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA	
\\C 05DE(D\ (\)\\	140	1400	1650	4.5	
VS-95PF(R)(W)	160	1600	1900	4.0	

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave		95 128	A °C	
Maximum RMS forward current	I _{F(RMS)}				149	A
	()	t = 10 ms	No voltage	Sinusoidal half wave, initial T _J = 150 °C	1700	А
Maximum peak, one cycle forward,		t = 8.3 ms	reapplied		1800	
non-repetitive surge current	IFSM	t = 10 ms	100 % V _{RRM} reapplied		1450	
		t = 8.3 ms			1500	
	l ² t	t = 10 ms	No voltage reapplied		14 500	A ² s
Maximum I ² t for fusing		t = 8.3 ms			13 500	
		t = 10 ms	100 % V _{RRM} reapplied		10 500	
		t = 8.3 ms			9400	
Maximum I $^2\sqrt{t}$ for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied		145 000	A²√s	
Low level value of threshold voltage	V _{F(TO)}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum		0.73	V	
Low level value of forward slope resistance	r _f	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		2.4	mΩ	
Maximum forward voltage drop	V_{FM}	I_{pk} = 267 A, T_J = 25 °C, t_p = 400 μ s rectangular wave		1.40	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to case	R _{thJC} DC operation		0.27	KAM	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	K/W	
Maximum allowable mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on nut (1)	3.4 (30)		
		Lubricated thread, tighting on nut (1)	2.3 (20)	N⋅m	
		Not lubricated thread, tighting on hexagon (2)	4.2 (37)	(lbf · in)	
		Lubricated thread, tighting on hexagon (2)	3.2 (28)		
Approximate weight			15.8	g	
Approximate weight			0.56	OZ.	
Case style		See dimensions - link at the end of datasheet DO-5 (DO-203/		D-203AB)	

Notes

⁽²⁾ Torque must be applicable only to hexagon and not to plastic structure, recommended for holed heatsink

△R _{thJC} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.14	0.10				
120°	0.16	0.17				
90°	0.21	0.22	$T_J = T_J \text{ maximum}$	K/W		
60°	0.30	0.31				
30°	0.50	0.50				

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

⁽¹⁾ Recommended for pass-through holes

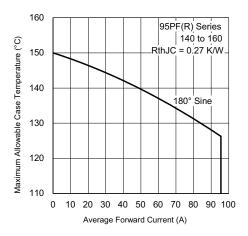


Fig. 1 - Current Ratings Characteristics

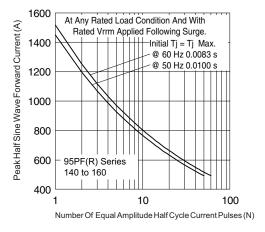


Fig. 2 - Maximum Non-Repetitive Surge Current

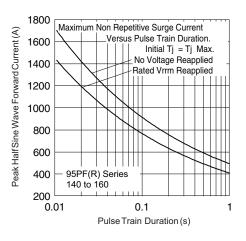


Fig. 3 - Maximum Non-Repetitive Surge Current

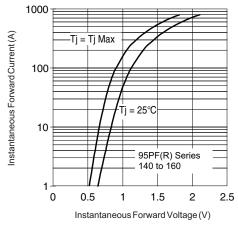


Fig. 4 - Forward Voltage Drop Characteristics

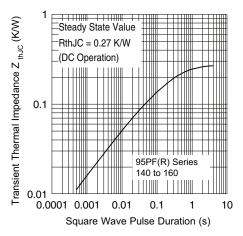


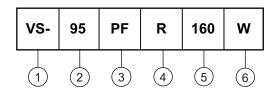
Fig. 5 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - 95 = standard device

PF = plastic package

None = stud normal polarity (cathode to stud)

• R = stud reverse polarity (anode to stud)

5 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

None = standard terminal
 (see dimensions for 95PF(R)... - link at the end of datasheet)

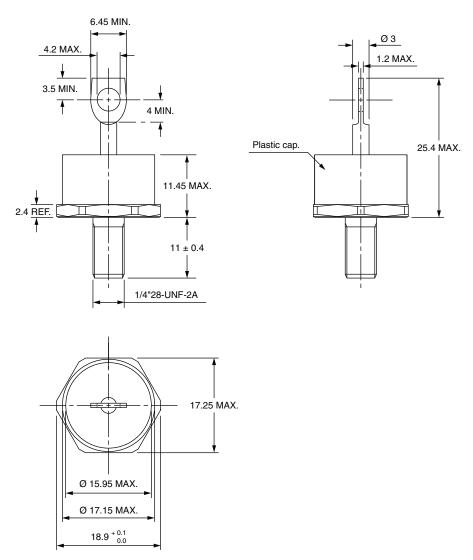
 W = wire terminal (see dimensions for 95PF(R)...W - link at the end of datasheet)

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95345	



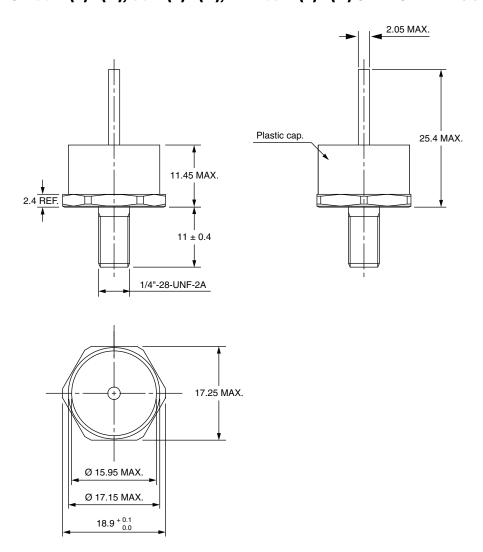
DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W), and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R), AND 95PF(R) SERIES in millimeters



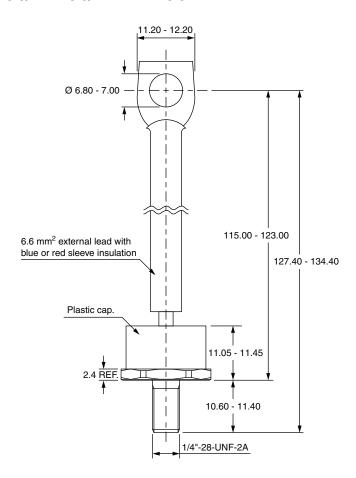


DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W), AND 95PF(R)...(W) SERIES in millimeters





DIMENSIONS FOR 52PF(R), 82PF(R), AND 97PF(R) SERIES in millimeters





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